## **ELECTRICAL CHARACTERISTICS**

Part Number	Working Voltage (Vw)	Breakdown Voltage (Vb)	Clamping Voltage (Vc)	Peak Current (Ip)	Transient Energy (Et)	Typical Capacitance (C)	
	Volt	Volt	Volt	Amp	Joule	pF	
	<50 μ A	1mA(DC)	2.5A,8/20 $\mu$ s	8/20 $\mu$ s	10/1000 $\mu$ s	1KHz	1MHz
JMV1206S330T551	33	39.0~47.0	75	180	1	550	0

- Vw- The max. steady state DC operating voltage of which varistor could maintain also not exceeding 50uA leakage current.
- Vb- The Voltage acrossed the device measured at 1mA DC current.
- Vc- The peak voltage acrossed the varistor measured at a specified pulse current and waveform.
- Ip- The max.peak current applied with specified wavefoem without any possibility of device fail.
- Et- The max. energy which dissipated with the specified waveform without any possibility of device fail.
- C The device capacitance measured with zero volt bias, 1.0Vrms and 1KHz / 0.5 V rms and 1 MHz.

MLV Storage condition→Temperature: ≤30°C/Humidity:≤60% RH(Moisture Sensitivity Levels: 2a)
MLV Preservation period→6 months

## **External Dimension**

Chip Dimension

				IIICH(IIIII)
Chip Size	L	W	Т	Α
1206	0.126±0.008	0.063±0.008	0.071max.	0.028max.
(3216)	(3.20±0.20)	(1.60±0.20)	(1.8max.)	(0.71max.)

